DATA SHEET



NPN SILICON RF TRANSISTOR NE85634 / 2SC3357 JEITA Part No.

NPN EPITAXIAL SILICON RF TRANSISTOR FOR HIGH-FREQUENCY LOW-NOISE AMPLIFICATION 3-PIN POWER MINIMOLD

FEATURES

- Low noise and high gain
- NF = 1.1 dB TYP., Ga = 7.5 dB TYP. @ VCE = 10 V, IC = 7 mA, f = 1 GHz
 NF = 1.8 dB TYP., Ga = 9.0 dB TYP. @ VCE = 10 V, IC = 40 mA, f = 1 GHz
- High power gain : MAG = 10 dB TYP. @ Ic = 40 mA, f = 1 GHz
 - Large Ptot : Ptot = 1.2 W (Mounted on 16 cm² × 0.7 mm (t) ceramic substrate)
 - Small package : 3-pin power minimold package

★ ORDERING INFORMATION

| Part Number | Quantity | Supplying Form |
|------------------------------|-------------------|--|
| NE85634-A 2SC3357-A | 25 pcs (Non reel) | 12 mm wide embossed taping Collector foce the performing eide of the tape |
| NE85634-T1-A 2SC3357-T1-A | 1 kpcs/reel | Collector face the perforation side of the tape |

Remark To order evaluation samples, contact your nearby sales office. The unit sample quantity is 25 pcs.

ABSOLUTE MAXIMUM RATINGS (TA = +25°C)

| Parameter | Symbol | Ratings | Unit |
|------------------------------|----------------------|-------------|------|
| Collector to Base Voltage | Vсво | 20 | V |
| Collector to Emitter Voltage | Vceo | 12 | V |
| Emitter to Base Voltage | Vebo | 3.0 | V |
| Collector Current | lc | 100 | mA |
| Total Power Dissipation | Ptot ^{Note} | 1.2 | W |
| Junction Temperature | Tj | 150 | °C |
| Storage Temperature | Tstg | -65 to +150 | °C |

Note Mounted on 16 $\text{cm}^2 \times 0.7 \text{ mm}$ (t) ceramic substrate

Caution Observe precautions when handling because these devices are sensitive to electrostatic discharge.

The information in this document is subject to change without notice. Before using this document, please confirm that this is the latest version.

THERMAL RESISTANCE

| Parameter | Symbol | Value | Unit |
|--------------------------------|----------------------------------|-------|------|
| Junction to Ambient Resistance | $R_{th \ (j-a)}{}^{\text{Note}}$ | 62.5 | °C/W |

Note Mounted on 16 cm² \times 0.7 mm (t) ceramic substrate

ELECTRICAL CHARACTERISTICS (TA = +25°C)

| Parameter | Symbol | Test Conditions | MIN. | TYP. | MAX. | Unit |
|------------------------------|-----------------------|---|------|------|------|------|
| DC Characteristics | | | | | | |
| Collector Cut-off Current | Ісво | $V_{CB} = 10 \text{ V}, \text{ I}_{E} = 0 \text{ mA}$ | - | - | 1.0 | μA |
| Emitter Cut-off Current | Ево | Vев = 1.0 V, Ic = 0 mA | - | - | 1.0 | μA |
| DC Current Gain | hfe Note 1 | Vce = 10 V, Ic = 20 mA | 50 | 120 | 250 | - |
| RF Characteristics | | | | | | |
| Gain Bandwidth Product | f⊤ | Vce = 10 V, Ic = 20 mA | - | 6.5 | - | GHz |
| Insertion Power Gain | S21e ² | Vce = 10 V, Ic = 20 mA, f = 1 GHz | - | 9.0 | - | dB |
| Noise Figure (1) | NF | Vce = 10 V, Ic = 7 mA, f = 1 GHz | - | 1.1 | - | dB |
| Noise Figure (2) | NF | Vce = 10 V, Ic = 40 mA, f = 1 GHz | - | 1.8 | 3.0 | dB |
| Reverse Transfer Capacitance | Cre ^{Note 2} | Vсв = 10 V, IE = 0 mA, f = 1 MHz | - | 0.65 | 1.0 | pF |

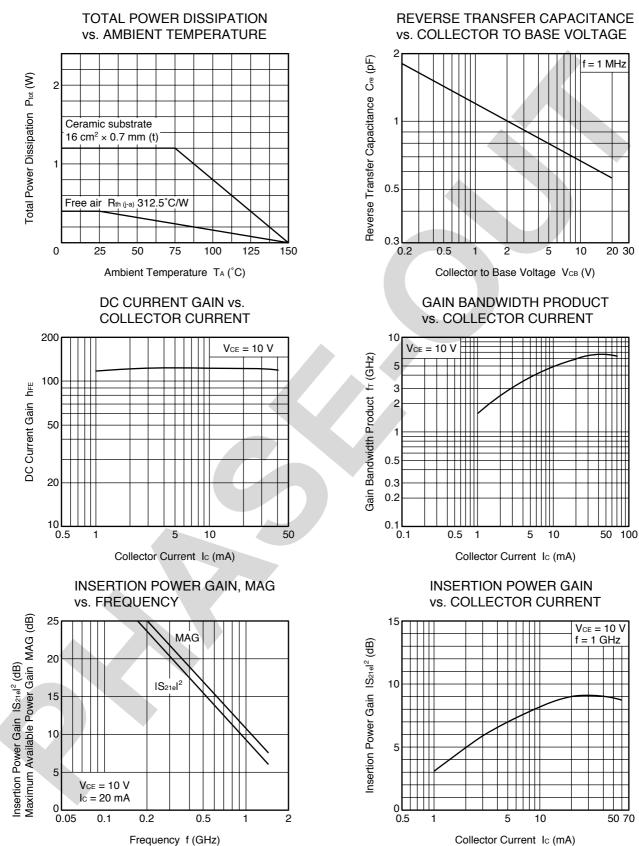
Notes 1. Pulse measurement: PW \leq 350 μ s, Duty Cycle \leq 2%

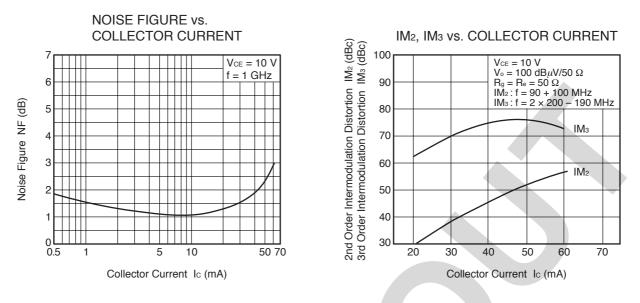
2. The emitter terminal and the case shall be connected to the guard terminal of the three-terminal capacitance bridge.

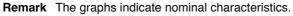
hfe CLASSIFICATION

| Rank | RH | RF | RE |
|-----------|-----------|-----------|------------|
| Marking | RH | RF | RE |
| hfe Value | 50 to 100 | 80 to 160 | 125 to 250 |

★ TYPICAL CHARACTERISTICS (T_A = +25°C, unless otherwise specified)





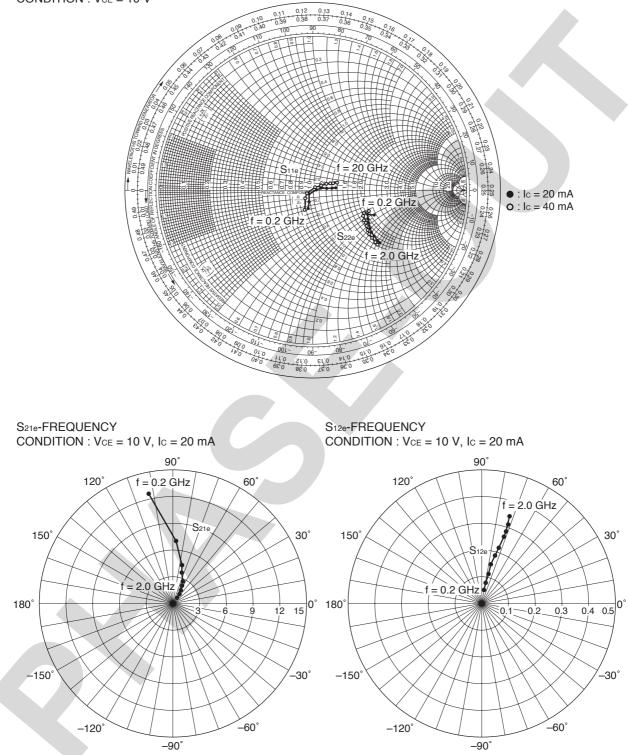


S-PARAMETERS

- S-parameters and noise parameters are provided on our Web site in a format (S2P) that enables the direct import of the parameters to microwave circuit simulators without the need for keyboard inputs.
- Click here to download S-parameters.
- [RF and Microwave] ® [Device Parameters]
- URL http://www.necel.com/microwave/en/

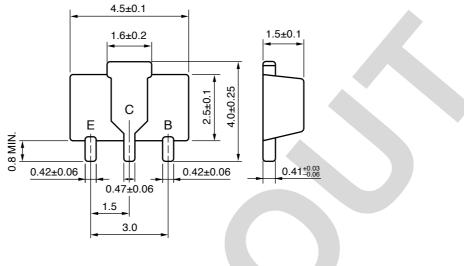
★ SMITH CHART

S11e, S22e-FREQUENCY CONDITION : VCE = 10 V



★ PACKAGE DIMENSIONS

3-PIN POWER MINIMOLD (UNIT: mm)



PIN CONNECTIONS

- E : Emitter
- C : Collector (Fin)
- B : Base
- (IEC : SOT-89)

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